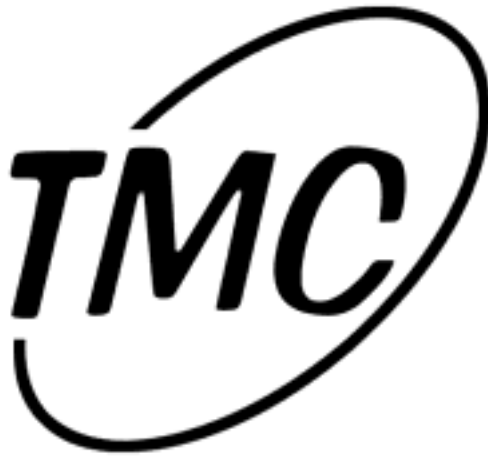


# 晶揚科技股份有限公司 Taiwan Micropaq Corporation

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## 承 認 書

### SPECIFICATION FOR APPROVAL

### **TM54S816T-6G**

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## Description

The **TM54S816T** is organized as 4-bank x 2097152-word x 16-bit(**8Mx16**), fabricated with high performance CMOS technology. Synchronous design allows precise cycle control with the use of system clock I/O transactions are possible on every clock cycle. Range of operating frequencies, programmable burst length and programmable latencies allow the same device to be useful for a variety of high bandwidth, high performance memory system applications.

## Features

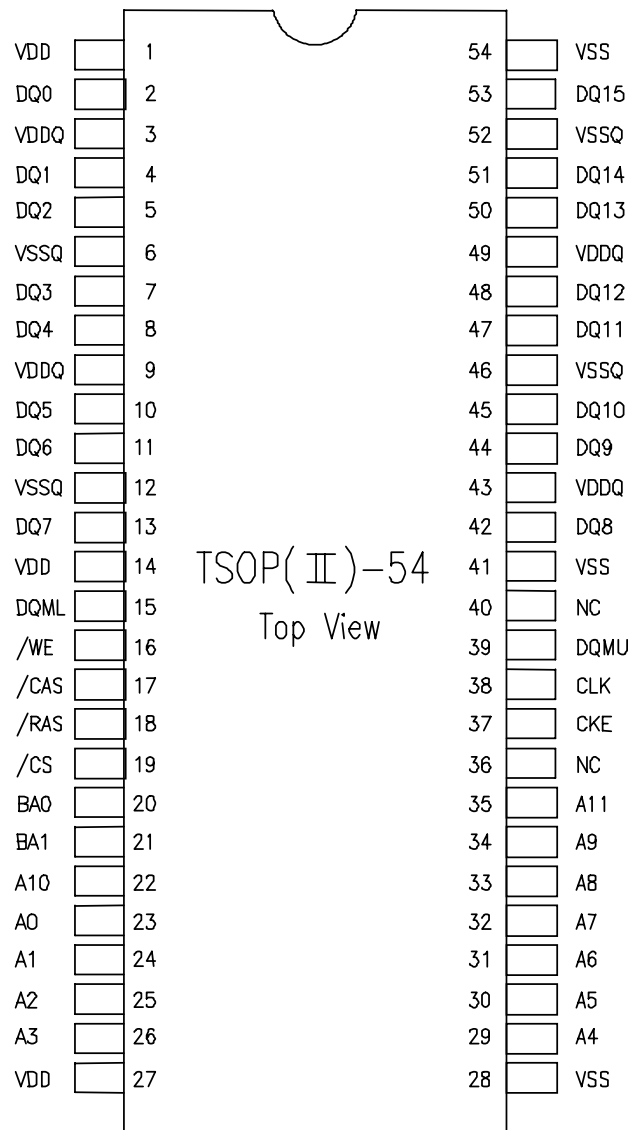
- Package: 400-mil 54-pin TSOP(II)
- JEDEC PC133/PC100 compatible
- Single 3.3V Power Supply
- LVTTTL Signal Compatible
- Programmable
  - CAS Latency (3 or 2 clocks)
  - Burst Length (1,2,4, 8 & full page)
  - Burst type (Sequential & Interleave)
- Burst read/write and burst read/single write operations capability
- Byte control(DQML and DQMU)
- Auto and Self Refresh
- 64ms refresh period (4K Refresh)
- 12-Row x 9-Column organization
- 4-Bank operation controlled by BA1,BA0
- Pin36 and 40 are “No Connected”
- Fully synchronous operation referenced to clock rising edge

## Frequency vs. AC Parameter

Symbol	Parameter	- 6G	- 7G	- 75G	Unit
$f_{CK3}$	Max. operating frequency @CL=3	166	143	133	Mhz
$f_{CK2}$	Max. operating frequency @CL=2	133	133	100	Mhz
$t_{CK3}$	Min. clock cycle time @CL=3	6.0	7.0	7.5	ns
$t_{AC3}$	Max. access time from CLK @CL=3	5.0	5.4	5.4	ns
$t_{CK2}$	Min. clock cycle time @CL=2	7.5	7.5	10	ns
$t_{AC2}$	Max. access time from CLK @CL=2	5.4	5.4	6.0	ns
$t_{rcd}$	Min. row to column delay	15	18	18	ns

## Pin Description

Pin Name	Function	Pin Name	Function
CLK	Master Clock	DQML/DQMU	Output Disable(Write Mask)
CKE	Clock Enable	A0-11	Address Input
/CS	Chip Select	BA1,BA0	Bank Address
/RAS	Row Address Strobe	Vdd	Power Supply
/CAS	Column Address Strobe	VddQ	Power Supply for Output
/WE	Write Enable	Vss/VssQ	Ground
DQ0-DQ15	Data I/O	NC	No Connection



**Pin Function**

<b>Pin</b>	<b>Name</b>	<b>Pin Function</b>
CLK	System clock	Active on the positive going edge to sample all inputs.
/CS	Chip select	Disables or enables device operation by masking or enabling all inputs except CLK,CKE and DQML/DQMU.
CKE	Clock enable	Masks system clock to freeze operation from the next clock cycle. CKE should be enabled at least one cycle prior to new command. Disable input buffers for power down in standby.
A0~A11	Address input	Row/column addresses are multiplexed on the same pins. Row address:A0~A11, Column address:A0~A7
BA1,BA0	Bank address	Selects bank to be activated during row address latch time. Selects bank for read/write during column address latch time.
/RAS	Row address strobe	Latches row addresses on the positive going edge of the CLK with /RAS low. Enables rows access & pre-charge.
/CAS	Column address strobe	Latches column addresses on the positive going edge of the CLK with /CAS low. Enables column access.
/WE	Write enable	Enables write operation and row pre-charge. Latches data in starting from /CAS,/WE active.
DQMU/DQML	Data I/O mask	Makes data output Hi-Z, Tshz after the clock and masks the output. Blocks data input when DQML/DQMU active.
DQ0~15	Data input/output	Data inputs/outputs are multiplexed on the same pins.
Vdd/Vss	Power supply/ground	Power and ground for the input buffers and the core logic.
VddQ/VssQ	Data output power / ground	Isolated power supply and ground for the output buffers to provide improved noise immunity.

NC/RFU	No connection / reserved for future use	This pin is recommended to be left no connection on the device.
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### Absolute maximum ratings

Parameter	Symbol	Ratings	Unit
Voltage on any pin relative to Vss	V <sub>IN</sub> , V <sub>OUT</sub>	-0.5 to 4.6	V
Voltage supply relative to Vss	V <sub>dd</sub> , V <sub>ddQ</sub>	-0.5 to 4.6	V
Operating temperature	T <sub>opr</sub>	0 to +70	
Power dissipation	P <sub>D</sub>	1	W
Output Shorted current	I <sub>OS</sub>	50	mA

### DC OPERATING CONDITIONS

Recommended operating conditions(Referenced to V<sub>ss</sub>=0V, T<sub>A</sub>=0 to 70 )

Parameter	Symbol	Min.	Typ.	Max.	Unit
Power Supply Voltage	V <sub>dd</sub> , V <sub>ddQ</sub>	3.0	3.3	3.6	V
Input Logic High Voltage	V <sub>IH</sub>	2.0	-	V <sub>dd</sub>	V
Input Logic Low Voltage	V <sub>IL</sub>	-0.3	-	0.8	V
Output Logic High Voltage	V <sub>OH</sub>	2.4	-	-	V
Output Logic Low Voltage	V <sub>OL</sub>	-	-	0.4	V
Input/Output Leakage Current	I <sub>IL</sub> , I <sub>OL</sub>	-5	-	5	μA

### DC Characteristics

(Recommended operating condition T<sub>A</sub> = 0 to 70 , unless otherwise noted.)

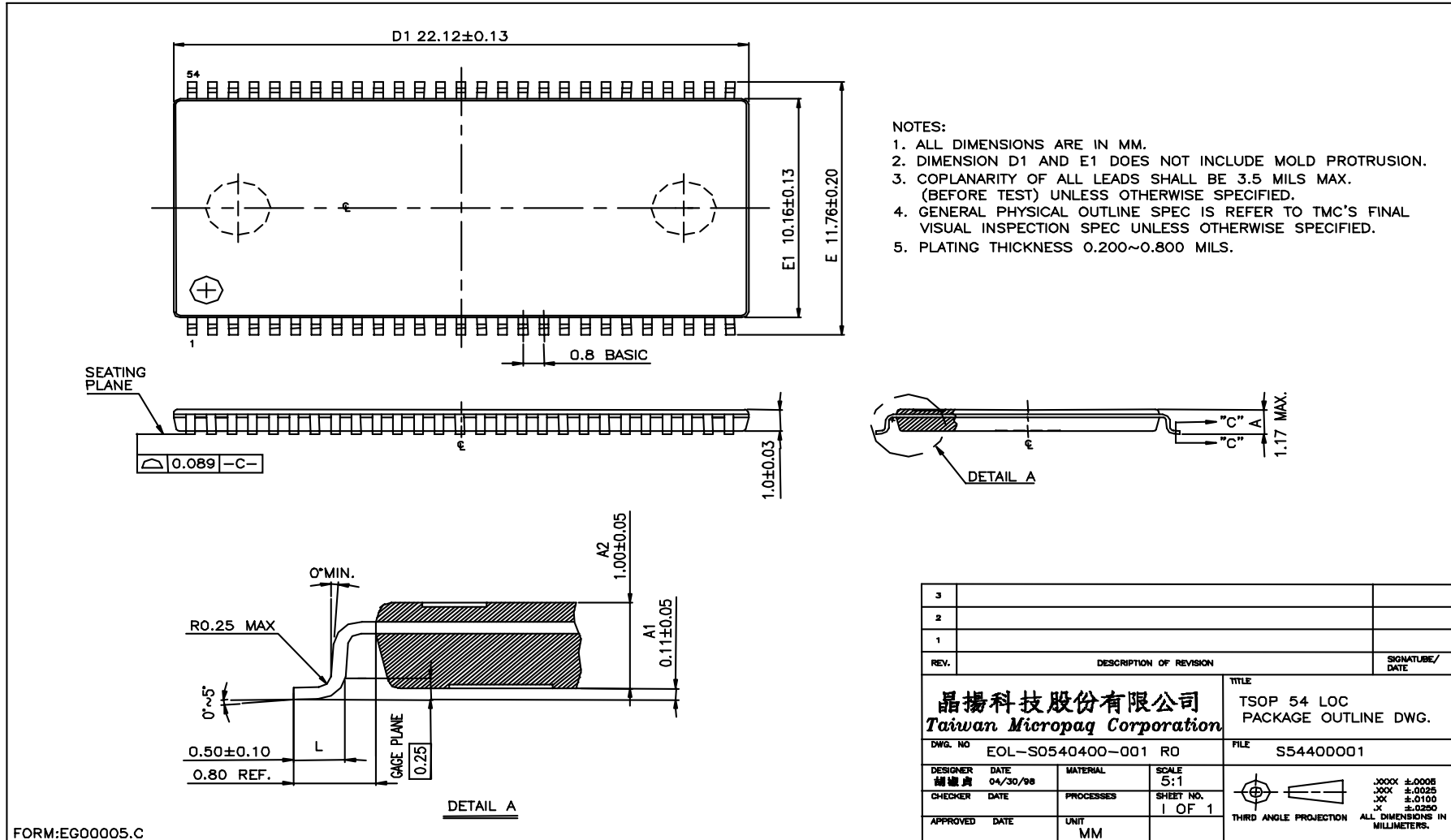
Parameter	Symbol	Test Conditions	Limits			Unit
			-6G	-7G	-75G	
Operating Current (One bank active)	I <sub>CC1</sub>	Burst length=1, CL=3, t <sub>RC</sub> = t <sub>RC</sub> (min), t <sub>CK</sub> = t <sub>CK</sub> (min)	120	110	100	mA
Pre-charge Standby Current in Power Down Mode	I <sub>CC2P</sub>	CKE < V <sub>IL</sub> (max), t <sub>CK</sub> = 15ns	2			mA
	I <sub>CC2PS</sub>	CKE & CLK < V <sub>IL</sub> (max)	2			
Pre-charge Standby Current in Non-Power Down Mode	I <sub>CC2N</sub>	/CS = CKE > V <sub>IH</sub> (min), t <sub>CK</sub> = 15ns	25			mA
	I <sub>CC2NS</sub>	/CS = CKE > V <sub>IH</sub> (min), CLK < V <sub>IL</sub> (max)	15			
Active Standby Current in Power Down Mode	I <sub>CC3P</sub>	CKE < V <sub>IL</sub> (max), t <sub>CK</sub> = 15ns	7			mA

	$I_{CC3PS}$	CKE & CLK < $V_{IL(max)}$	5			
Active Standby Current in Non-Power Down Mode	$I_{CC3N}$	/CS=CKE > $V_{IH(min)}$ , $t_{CK} = 15ns$	35			mA
	$I_{CC3NS}$	/CS=CKE > $V_{IH(min)}$ , CLK < $V_{IL(max)}$	30			
Operating Current (Burst)	$I_{CC4}$	BL=4,CL=3,All Banks Active	160	150	140	mA
Auto Refresh Current	$I_{CC5}$	CBR Command, $t_{CK} = t_{CK(min)}$	160	150	140	mA
Self Refresh Current	$I_{CC6}$	CKE < 0.2V	2			mA

### AC Characteristics

Recommended operating conditions ( $V_{dd} = V_{ddQ} = 3.3V, V_{ss} = 0V, T_A = 0$  to  $70$  )

	Symbol	Parameter	-6G		-7G		-75G		Unit
			Min	Max	Min	Max	Min	Max	
1	$f_{CK3}$	Clock Frequency, CL=3		166		143		133	Mhz
2	$f_{CK2}$	Clock Frequency, CL=2		133		133		100	Mhz
3	$t_{CK3}$	Clock Cycle Time, CL=3	6.0		7.0		7.5		ns
4	$t_{CK2}$	Clock Cycle Time, CL=2	7.5		7.5		10		ns
5	$t_{AC3}$	Clock Access Time, CL=3		5.0		5.4		5.4	ns
6	$t_{AC2}$	Clock Access Time, CL=2		5.4		5.4		6.0	ns
7	$t_{CH}$	Clock High Pulse Width	2.5		2.5		2.5		ns
8	$t_{CL}$	Clock Low Pulse Width	2.5		2.5		2.5		ns
9	$t_{IS}$	Input Setup time(all inputs)	1.5		1.5		1.5		ns
10	$t_{IH}$	Input Hold time(all inputs)	0.8		0.8		0.8		ns
11	$t_{OH}$	Data-out Hold time	1.5		1.8		1.8		ns
12	$t_T$	Transition time of clock	1.0	10	1.0	10	1.0	10	ns
13	$t_{RCD}$	Row to Column delay	15		18		18		ns
14	$t_{RC}$	Row Cycle time	60		63		63		ns
15	$t_{RAS}$	Row active time	42		42		42		ns
16	$t_{RP}$	Row Pre-charge time	15		18		18		ns
17	$t_{RRD}$	Row active to active delay	12		14		14		ns
18	$t_{REF}$	Refresh time	64		64		64		ms



3		
2		
1		
REV.	DESCRIPTION OF REVISION	SIGNATURE/DATE
晶揚科技股份有限公司 Taiwan Micropaq Corporation		TITLE TSOP 54 LOC PACKAGE OUTLINE DWG.
DWG. NO EOL-S0540400-001 RO		FILE S54400001
DESIGNER	DATE	MATERIAL
胡建興	04/30/98	
CHECKER	DATE	PROCESSES
APPROVED	DATE	UNIT
		MM
SCALE 5:1		SHEET NO. 1 OF 1
THIRD ANGLE PROJECTION		J000X ±.0005 J00X ±.0025 J0X ±.010 JX ±.0250 ALL DIMENSIONS IN MILLIMETERS.